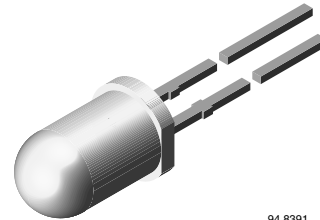


## Silicon NPN Phototransistor

### Description

BPW96 is a high speed and high sensitive silicon NPN epitaxial planar phototransistor in a standard T-1 $\frac{3}{4}$  ( $\varnothing$  5 mm) package. Due to its waterclear epoxy the device is sensitive to visible and near infrared radiation.

The viewing angle of  $\pm 20^\circ$  makes it insensible to ambient straylight.



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### Features

- Fast response times
- High photo sensitivity
- Standard T-1 $\frac{3}{4}$  ( $\varnothing$  5 mm) clear plastic package
- Angle of half sensitivity  $\varphi = \pm 20^\circ$
- Suitable for visible and near infrared radiation
- Selected into sensitivity groups
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### Applications

- Detector in electronic control and drive circuits

### Absolute Maximum Ratings

$T_{amb} = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Collector Emitter Voltage		$V_{CEO}$	70	V
Emitter Collector Voltage		$V_{ECO}$	5	V
Collector current		$I_C$	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10 \text{ ms}$	$I_{CM}$	100	mA
Total Power Dissipation	$T_{amb} \leq 47^\circ\text{C}$	$P_{tot}$	150	mW
Junction Temperature		$T_j$	100	$^\circ\text{C}$
Storage Temperature Range		$T_{stg}$	- 55 to + 100	$^\circ\text{C}$
Soldering Temperature	$t \leq 3 \text{ s}$	$T_{sd}$	260	$^\circ\text{C}$
Thermal Resistance Junction/ Ambient		$R_{thJA}$	350	K/W

### Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector Emitter Breakdown Voltage	$I_C = 1\text{ mA}$	$V_{(BR)CEO}$	70			V
Collector-emitter dark current	$V_{CE} = 20\text{ V}, E = 0$	$I_{CEO}$		1	200	nA
Collector-emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}, E = 0$	$C_{CEO}$		3		pF

### Optical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Angle of Half Sensitivity		$\phi$		$\pm 20$		deg
Wavelength of Peak Sensitivity		$\lambda_p$		850		nm
Range of Spectral Bandwidth		$\lambda_{0.5}$		620 to 980		nm
Collector Emitter Saturation Voltage	$E_e = 1\text{ mW/cm}^2, \lambda = 950\text{ nm}, I_C = 0.1\text{ mA}$	$V_{CEsat}$			0.3	V
Turn-On Time	$V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\ \Omega$	$t_{on}$		2.0		$\mu\text{s}$
Turn-Off Time	$V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\ \Omega$	$t_{off}$		2.3		$\mu\text{s}$
Cut-Off Frequency	$V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\ \Omega$	$f_c$		180		kHz

### Type Dedicated Characteristics

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Collector Light Current	$E_e = 1\text{ mW/cm}^2, \lambda = 950\text{ nm}, V_{CE} = 5\text{ V}$	BPW96A	$I_{ca}$	1.5	2.5	4.5	mA
		BPW96B	$I_{ca}$	2.5	4.5	7.5	mA
		BPW96C	$I_{ca}$	4.5	8	15	mA

### Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified

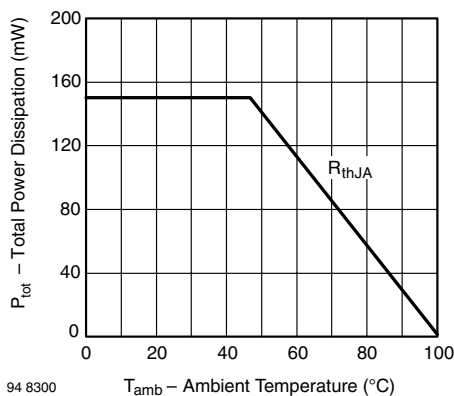


Figure 1. Total Power Dissipation vs. Ambient Temperature

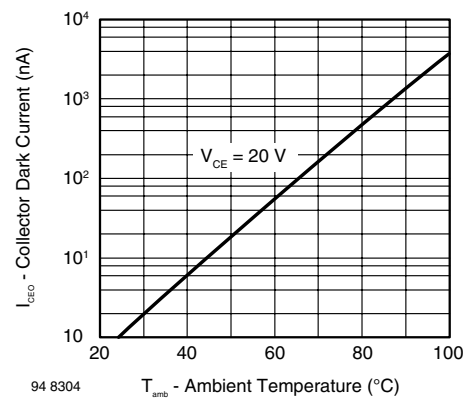


Figure 2. Collector Dark Current vs. Ambient Temperature

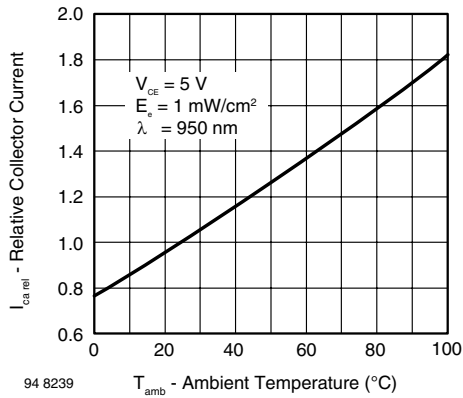


Figure 3. Relative Collector Current vs. Ambient Temperature

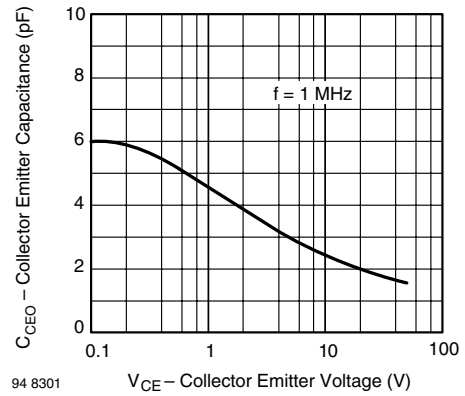


Figure 6. Collector Emitter Capacitance vs. Collector Emitter Voltage

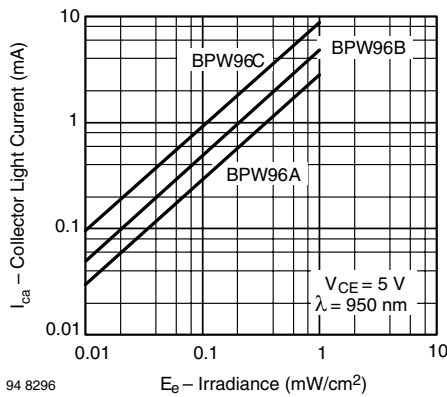


Figure 4. Collector Light Current vs. Irradiance

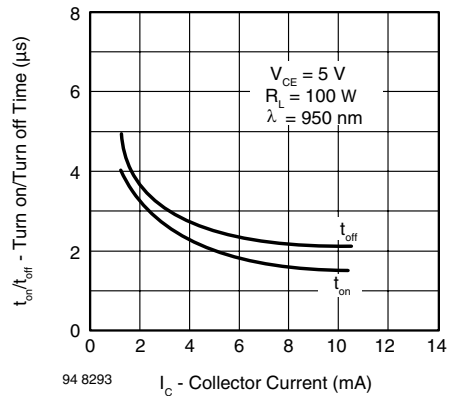


Figure 7. Turn On/Turn Off Time vs. Collector Current

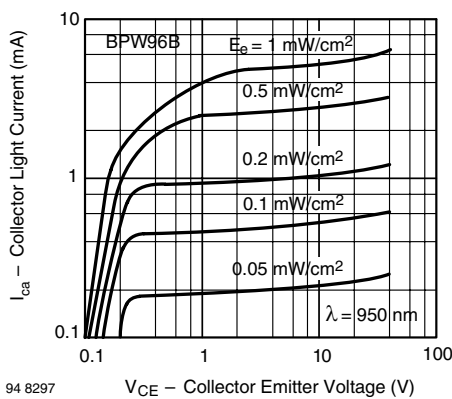


Figure 5. Collector Light Current vs. Collector Emitter Voltage

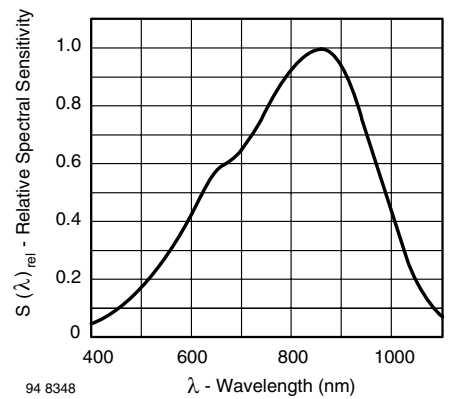
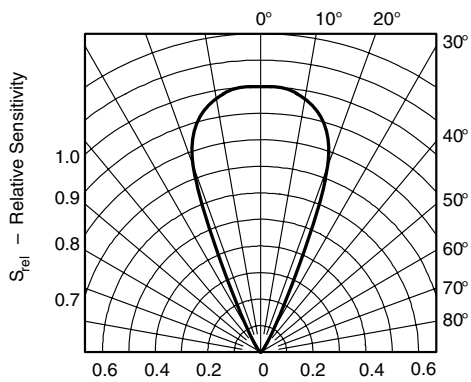


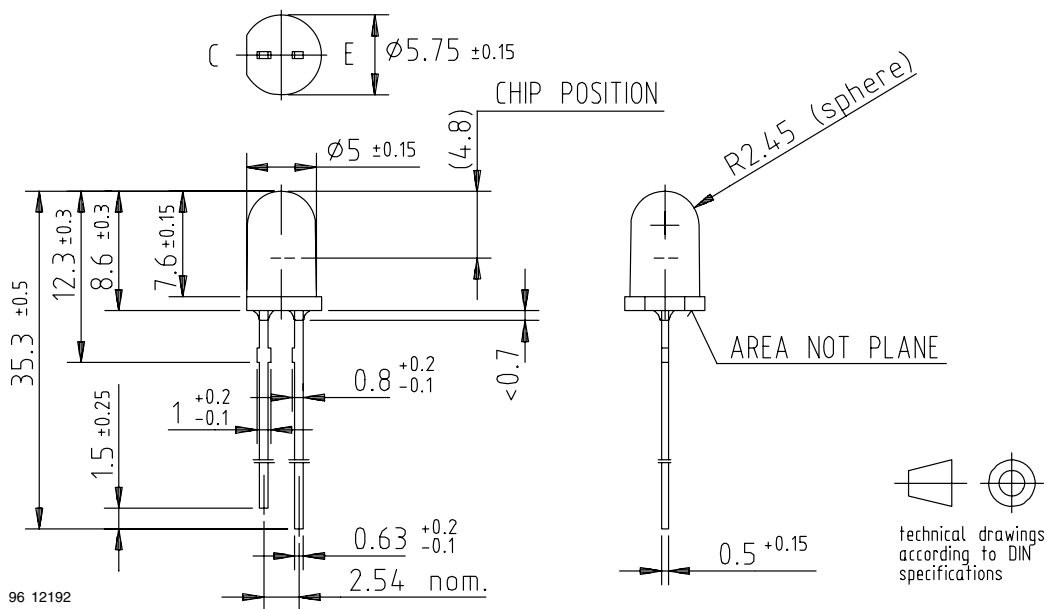
Figure 8. Relative Spectral Sensitivity vs. Wavelength



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Figure 9. Relative Radiant Sensitivity vs. Angular Displacement

## Package Dimensions in mm



96 12192



## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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